- 11 -

## CLAIMS:

- 1. A thermal sensor circuit for sensing the temperature of an integrated circuit chip, the thermal sensor circuit including:
- an output comparator for comparing a reference voltage,  $V_{ref}$ , with a sensed voltage,  $V_{sense}$ , the sensed voltage being measured from a sensing device;
  - a first circuit to which a reference voltage line is connected to measure V<sub>ref</sub>;
  - a first current mirror providing a first current input to the first circuit and to a compensation circuit;
- a second current mirror providing a second current input to the compensation circuit and to the sensing device; and wherein

the compensation circuit provides a current gain, defined as the ratio of the second current input to the first current input, for compensating for variations in V<sub>ref</sub> due to variations of the characteristics of the thermal sensing circuit arising from manufacture by adjusting the second current input in dependence on the variations of the characteristics to thereby vary V<sub>sense</sub> with V<sub>ref</sub>.

- 2. The thermal sensor circuit of claim 1, wherein the compensation circuit includes first, second, third and fourth bipolar junction transistors (BJTs) and wherein:
- the first BJT has a collector terminal connected to the first current input of the first current mirror, a base terminal connected to a common base connection and an emitter terminal connected to ground;

the second BJT has a collector terminal connected to the second current input of the second current mirror, a base terminal connected to the common base connection and an emitter terminal connected to ground;

the third BJT has a collector terminal connected to the second current input, a base terminal connected the first current input and an emitter connected to the common base connection;

the fourth BJT has a collector terminal connected to a voltage supply of the thermal sensor circuit, a base terminal connected to the common base connection and an emitter terminal connected to ground; and

- 12 -

the ratio of emitter area of the fourth BJT to the emitter areas of the first, second and third BJTs is N:1, where N>0.

3. The thermal sensor circuit of claim 2, wherein the first circuit includes fifth and sixth 5 BJTs, and wherein:

the fifth BJT has a collector terminal connected to the first current input, a base terminal connected to the reference voltage line and an emitter terminal connected to an output point of the first circuit via a first resistor;

the sixth BJT has a collector terminal connected to the first current input, a base terminal connected to the reference voltage line and an emitter connected to the output point of the first circuit; and

the output point of the first circuit is connected to ground via a second resistor.

- 4. The thermal sensor circuit of claim 3, wherein the ratio of emitter area of the fifth BJT to the emitter area of the sixth BJT is M:1, where M>1.
- The thermal sensor circuit of claim 3 or claim 4, wherein each of the first to sixth BJTs is an n-p-n transistor.
  - 20 6. The thermal sensor circuit of claim 3 or claim 4, wherein the current gain is given by:

$$\frac{I2}{I1} = \frac{\beta^2 + (3+N)\beta}{\beta^2 + \beta + (2+N)}$$

where:

Il is the first current input;

12 is the second current input; and

 $\beta$  is the common-emitter current gain of each of the first to sixth BJTs.

7. The thermal sensor circuit of claim 2, wherein the first and second current mirrors are connected to the voltage supply of the thermal sensor circuit and use p-n-p BJTs to supply the first and second current inputs, respectively.

Add A2>

25